



# F1T1 THRU F1T7

## 1.0 AMP. Fast Recovery Rectifiers

	<b>Voltage Range</b> 50 to 1000 Volts <b>Current</b> 1.0 Ampere
--	--

<p><b>Features</b></p> <ul style="list-style-type: none"> <li>✧ Low forward voltage drop</li> <li>✧ High current capability</li> <li>✧ High reliability</li> <li>✧ High surge current capability</li> </ul> <p><b>Mechanical Data</b></p> <ul style="list-style-type: none"> <li>✧ Cases: Molded plastic</li> <li>✧ Epoxy: UL 94V-0 rate flame retardant</li> <li>✧ Lead: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed</li> <li>✧ Polarity: Color band denotes cathode end</li> <li>✧ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension</li> <li>✧ Weight: 0.20 gram</li> </ul>	<p><b>TS-1</b></p> <p style="text-align: center;"><b>Dimensions in inches and (millimeters)</b></p>
--	---

### Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%

Type Number	Symbol	F1T1	F1T2	F1T3	F1T4	F1T5	F1T6	F1T7	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length @ $T_A = 55^\circ C$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	30							A
Maximum Instantaneous Forward Voltage @ 1.0A	$V_F$	1.2							V
Maximum DC Reverse Current @ $T_A = 25^\circ C$ at Rated DC Blocking Voltage @ $T_A = 100^\circ C$	$I_R$	5.0 100							$\mu A$ $\mu A$
Maximum Reverse Recovery Time ( Note 1 )	$T_{rr}$	150				250	500		nS
Typical Junction Capacitance ( Note 2 )	$C_j$	10							pF
Typical Thermal Resistance ( Note 3 )	$R_{\theta JA}$	100							$^\circ C/W$
Operating Temperature Range	$T_J$	-65 to +150							$^\circ C$
Storage Temperature Range	$T_{STG}$	-65 to +150							$^\circ C$

Notes: 1. Reverse Recovery Test Conditions:  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$   
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.  
 3. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

## RATINGS AND CHARACTERISTIC CURVES (F1T1 THRU F1T7)

FIG.1- MAXIMUM TYPICAL FORWARD CURRENT DERATING CURVE

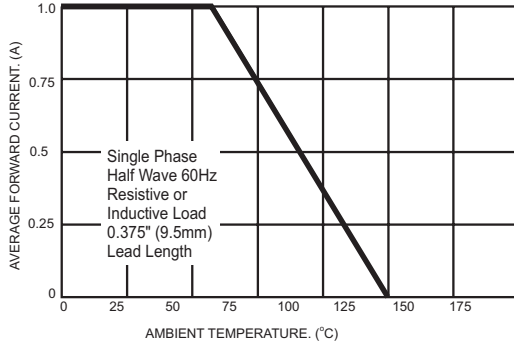


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

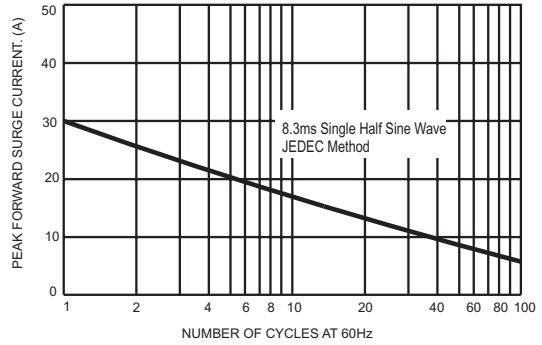


FIG.3- TYPICAL FORWARD CHARACTERISTICS

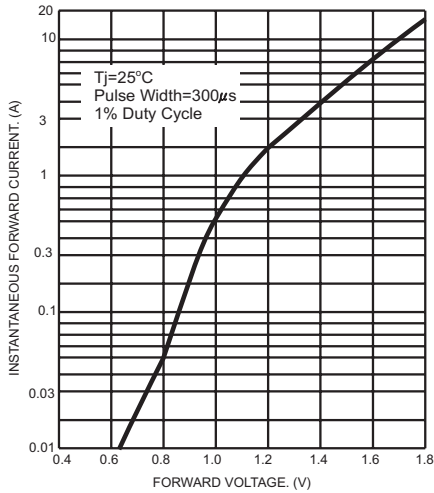


FIG.4- TYPICAL JUNCTION CAPACITANCE

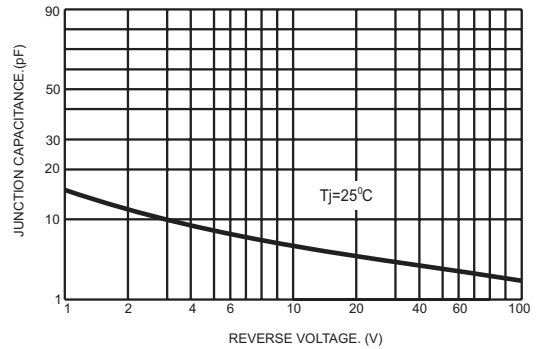
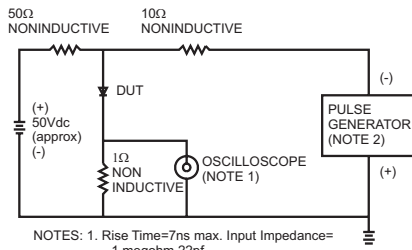


FIG.5- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



- NOTES: 1. Rise Time=7ns max. Input Impedance= 1 megohm 22pf  
2. Rise Time=10ns max. Source Impedance= 50 ohms

